TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSIII)

2SK2604

Switching Regulator Applications

• Low drain-source ON resistance : RDS (ON) = 1.9 Ω (typ.)

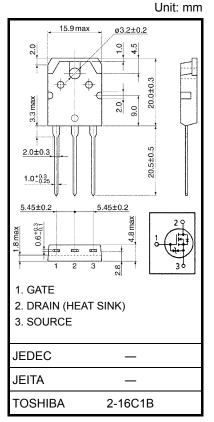
• High forward transfer admittance $|Y_{fs}| = 3.8 \text{ S (typ.)}$

• Low leakage current : $I_{DSS} = 100 \,\mu\text{A} \,(\text{max}) \,(V_{DS} = 640 \,\text{V})$

• Enhancement mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V (Vps} = 10 \text{ V, Ip} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

| Characteris | stics | Symbol | Rating | Unit | |
|-------------------------|------------------------|------------------|------------|------|--|
| Drain-source voltage | | V_{DSS} | 800 | V | |
| Drain-gate voltage (Ro | _{SS} = 20k Ω) | V_{DGR} | 800 | V | |
| Gate-source voltage | | V _{GSS} | ±30 | V | |
| Drain current | DC (Note 1) | ΙD | 5 | Α | |
| | Pulse (Note 1) | I _{DP} | 15 | Α | |
| Drain power dissipation | n (Tc = 25°C) | P _D | 125 | W | |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 370 | mJ | |
| Avalanche current | | I _{AR} | 5 | Α | |
| Repetitive avalanche e | nergy (Note 3) | E _{AR} | 12.5 | mJ | |
| Channel temperature | | T _{ch} | 150 | °C | |
| Storage temperature ra | ange | T _{stg} | -55 to 150 | °C | |



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-----|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 1.0 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 50 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 27 mH, R_G = 25 Ω , I_{AR} = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



Electrical Characteristics (Ta = 25°C)

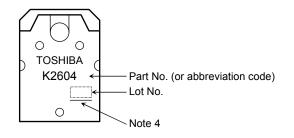
| Charac | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|----------------------|--|-----|------|-----|------|
| Gate leakage cu | ırrent | I _{GSS} | V _{GS} = ±30 V, V _{DS} = 0 V | | _ | ±10 | μΑ |
| Gate-source bro | eakdown voltage | V (BR) GSS | I _G = ±10 μA, V _{DS} = 0 V | ±30 | _ | _ | V |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 640 V, V _{GS} = 0 V | _ | _ | 100 | μΑ |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 800 | _ | _ | V |
| Gate threshold v | /oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | _ | 4.0 | V |
| Drain-source O | N resistance | R _{DS} (ON) | V _{GS} = 10 V, I _D = 3 A, | _ | 1.9 | 2.2 | Ω |
| Forward transfe | r admittance | Y _{fs} | V _{DS} = 15 V, I _D = 3 A | | 3.8 | _ | S |
| Input capacitano | ce | C _{iss} | | | 1080 | _ | pF |
| Reverse transfer capacitance | | C _{rss} | V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz | _ | 16 | _ | |
| Output capacitance | | Coss | | | 105 | _ | |
| Switching time | Rise time | t _r | $V_{GS} = \frac{10V}{0V} = \frac{I_D = 3A}{V_{out}} V_{out}$ $V_{CS} = \frac{10V}{0V} = \frac{10}{V_{out}} = \frac{10}{V_{out}}$ $V_{DD} = \frac{10V}{V_{out}} = \frac{10}{V_{out}}$ $V_{DD} = \frac{10V}{V_{out}} = \frac{10}{V_{out}}$ $V_{DD} = \frac{10V}{V_{out}} = \frac{10}{V_{out}}$ | _ | 40 | _ | |
| | Turn-on time | t _{on} | | _ | 80 | _ | ne |
| | Fall time | t _f | | _ | 40 | _ | ns |
| | Turn-off time | t _{off} | | _ | 140 | _ | |
| Total gate charge (gate-source plus gate-drain) | | Qg | V _{DD} ≈ 400 V, V _{GS} = 10 V, I _D = 5 A | | 34 | | nC |
| Gate-source charge | | Q _{gs} | | | 16 | | |
| Gate-drain ("miller") Charge | | Q_{gd} | | _ | 18 | _ | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 5 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 15 | Α |
| Forward voltage (diode) | V_{DSF} | I _{DR} = 5 A, V _{GS} = 0 V | _ | _ | -1.9 | ٧ |
| Reverse recovery time | t _{rr} | I _{DR} = 5 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs | ı | 1000 | - | ns |
| Reverse recovery charge | Q_{rr} | iDR = 3 A, VGS = 0 V, diDR / dt = 100 A / μs | 1 | 7.5 | | μC |

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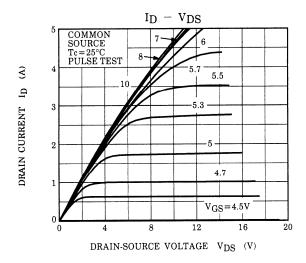
Marking

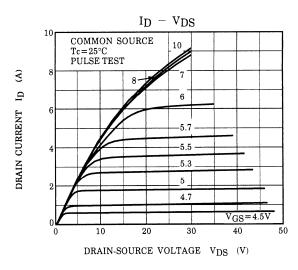


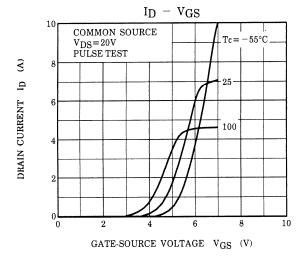
Note 4: A line under a Lot No. identifies the indication of product Labels.

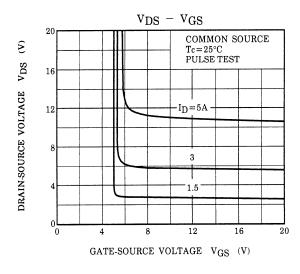
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

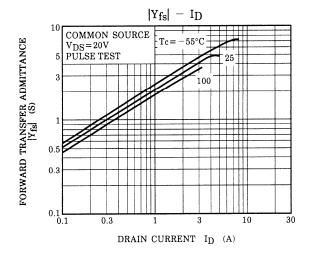
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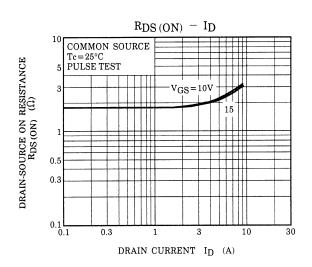




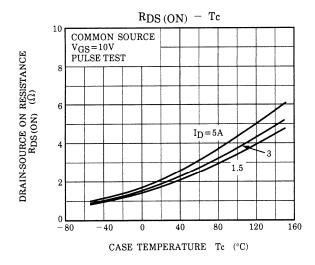


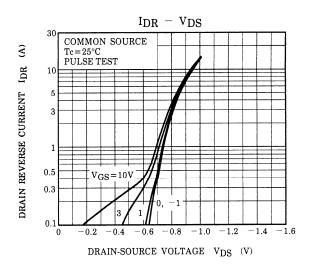


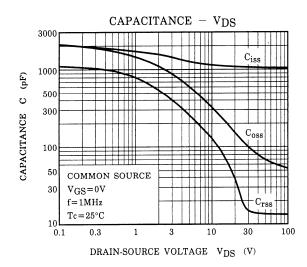


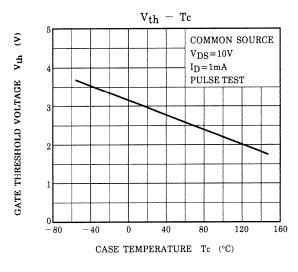


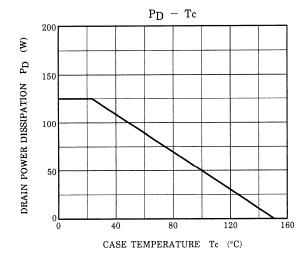
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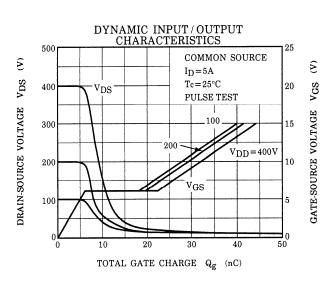




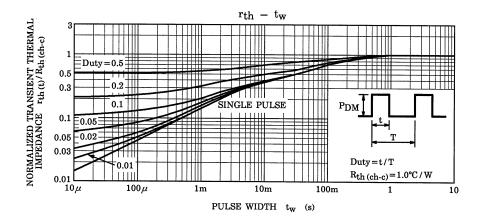


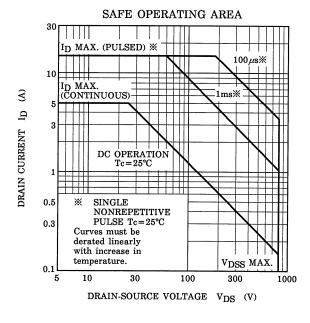


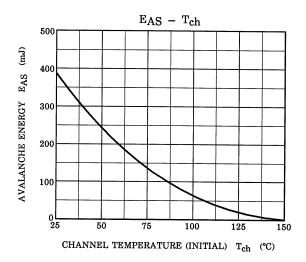


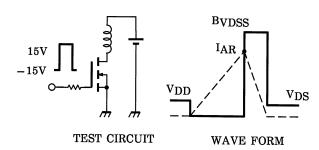


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$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 90~V,~L = 27~mH \end{aligned} \qquad E_{AS} &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right) \end{aligned}$$

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